

1MBI200HH-120L-50

IGBT Modules

IGBT MODULE 1200V / 200A / 1 in one package

■ Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter DB for Motor Drive AC and DC Servo Drive Amplifier (DB) Active PFC Industrial machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage		Vces			1200	V	
Gate-Emitter voltage		V _{GES}			±20	V	
Collector current		Ic	Continuous	Tc=25°C	300		
			Continuous	Tc=80°C	200		
		Іср	1ms	Tc=25°C	600	^	
			IIIIS	Tc=80°C	400	Α	
		-lc			75		
		-lc pluse	1ms		150		
Collector Power Dissipation		Pc	1 device		1390	W	
Reverse voltage for FWD		VR			1200	V	
Forward current for FWD		l _F	Continuous		200	Α	
		F pulse	1ms		400		
Junction temperature		Tj			+150	°C	
Storage temperature		T _{stg}			-40 to +125		
Isolation voltage	between terminal and copper base (*1)	V _{iso}	AC : 1min.		2500	VAC	
	between thermistor and others (*2)	V iso	AC . IIIIII.		2500	VAC	
Screw Torque	Mounting (*3)			3.5	Nim		
	Terminals (*4)]-			4.5	Nm	

Note *1: All terminals should be connected together when isolation test will be done.

Note *2: Two thermistor terminals should be connected together, each other terminals should be connected together and shorted to base plate when isolation test will be done.

Note *3: Recommendable Value: Mounting 2.5 to 3.5 Nm (M5 or M6)

Note *4: Recommendable Value: Terminals 3.5 to 4.5 Nm (M6)

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● Electrical characteristics (at T_j= 25°C unless otherwise specified)

Items		Symbols	Conditions	Conditions		Characteristics		
		Syllibols	Conditions			typ.	max.	Units
IGBT+Inverse Diode	Zero gate voltage collector current	Ices	V _{CE} = 1200V V _{GE} = 0V			-	2.0	mA
	Gate-Emitter leakage current	Iges				-	400	nA
	Gate-Emitter threshold voltage	V _{GE(th)}	-			6.2	6.7	V
	Collector-Emitter saturation voltage	V _{CE(sat)}		T _j = 25°C	-	3.25	3.55	
		(terminal)	Ic = 200A	T _j =125°C	-	4.15	-	V
		V _{CE(sat)}	V _{GE} =15V	$T_j = 25^{\circ}C$	-	3.10	3.40	
		(chip)		T _j =125°C	-	4.00	-	
	Input capacitance	Cies	Vce=10V,Vge=0V,f=1I	MHz	-	18	-	nF
	Turn-on time	ton	V _{cc} = 600V		-	0.20	0.50	μs
		tr	Ic = 200A		-	0.10	0.40	
		t r (i)	V _{GE} = ±15V		-	0.30	-	
	Turn-off time	toff	R _G = 3.1 Ω				0.70	
		t _f	Ls = 20nH		-	0.05	0.20	
	Forward on voltage	VF		T _j = 25°C	-	1.80	2.30	- V
		(terminal)	I _F = 75A	T _j =125°C	-	1.95	-	
		VF	V _{GE} =0V	T _j = 25°C	-	1.70	2.15	
		(chip)		T _j =125°C	-	1.85	-	
	Reverse Current	I _R	V _{CE} = 1200V	V _{CE} = 1200V		-	1.0	mA
FWD	Forward on voltage	VF		T _j = 25°C	-	8.15	9.40	V
		(terminal)	I _F = 200A V _{GE} =0V	T _j =125°C	-	4.45	-	
		VF		$T_j = 25^{\circ}C$	-	7.90	9.15	
		(chip)		T _j =125°C	-	4.20	-	
	Reverse recovery time	trr	I _F = 200A		-	-	0.20	μs
	Lead resistance, terminal-chip (*5)				-	0.70	-	mΩ
stor	Resistance	R	T = 25°C			5000	-	Ω
Thermistor		K	T = 125°C			495	520	
The	B value	В	T = 25/50°C		3305	3375	3450	K

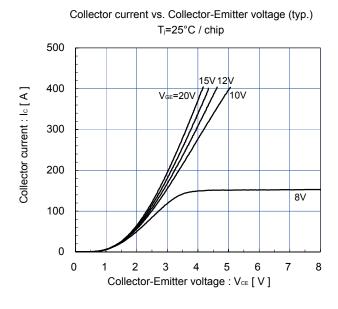
Note *5: Biggest internal terminal resistance among arm.

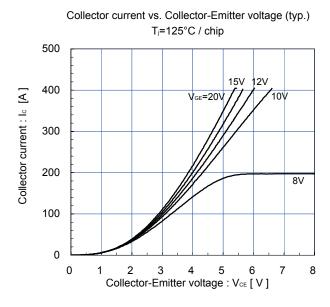
● Thermal resistance characteristics

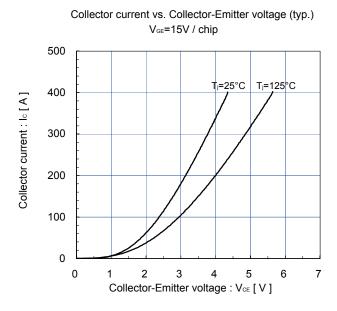
Items	Symbols	Conditions	Characteristics			Units
items	Syllibols	Conditions	min.	typ.	max.	Ullits
	R _{th(j-e)}	IGBT	-	-	0.067	°C/W
Thermal resistance(1device)		Inverse Diode	-	-	0.460	
		FWD	-	-	0.150	
Contact Thermal resistance	R _{th(c-f)}	with Thermal Compound (*6)	-	0.0250	-	

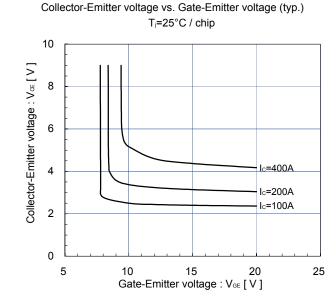
Note *6: This is the value which is defined mounting on the additional cooling fin with thermal compound.

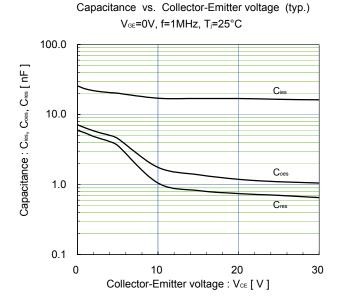
■ Characteristics (Representative)

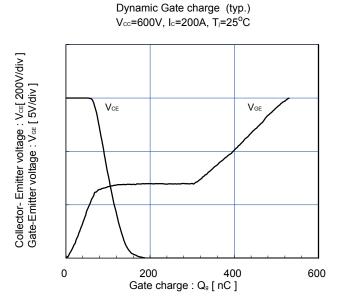


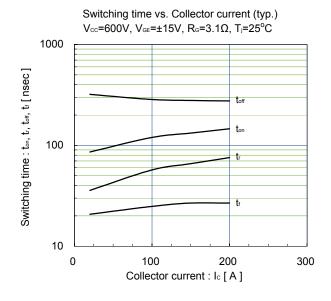


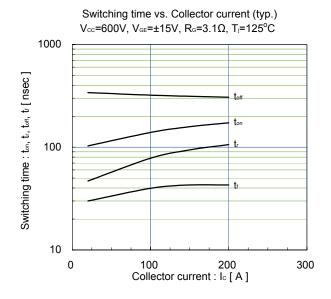


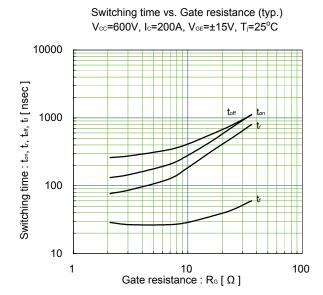


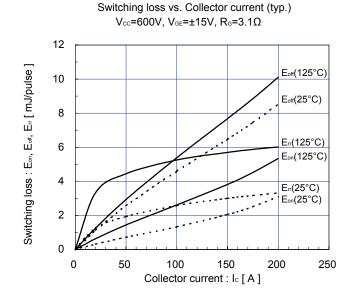


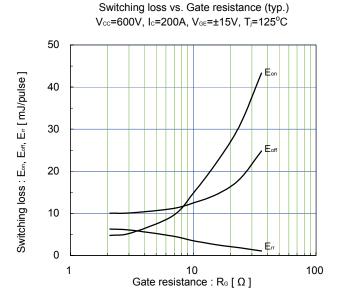


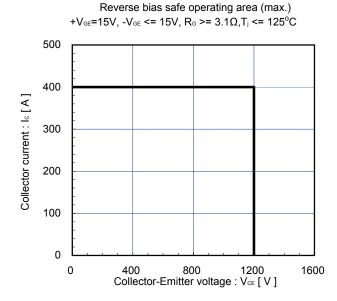


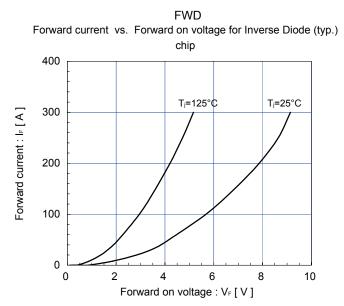


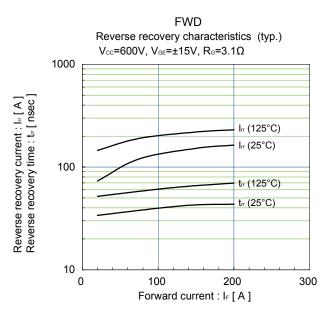


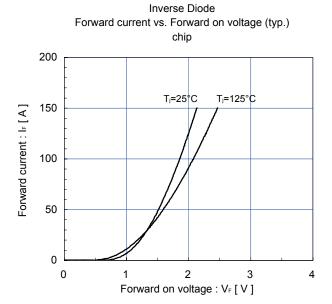


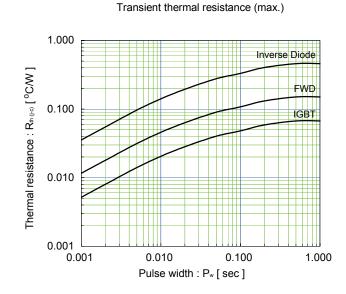


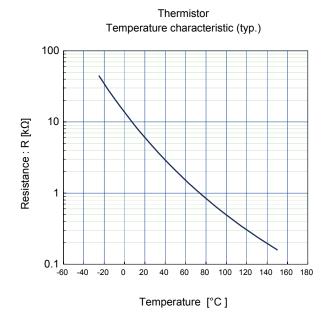




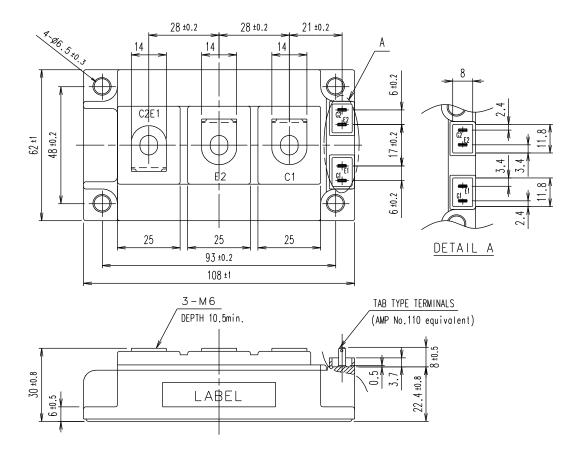




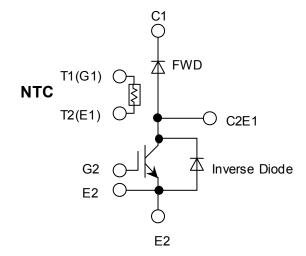




■ Outline Drawings, mm



■ Equivalent Circuit Schematic



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- OA equipment
- Communications equipment (terminal devices)
- Measurement equipment

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- Safety devices
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